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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	59
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LFQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f2136csdfp-30

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

1.1.2 Specifications

Tables 1.1 and 1.2 outline Specifications.

ltem	- Eunction	Description
	Control	Description
CPU	Central	R&C CPU core
	processing unit	Minimum instruction execution time:
		50 ps (CPL clock = 20 MHz \sqrt{CC} = 2.7 V to 5.5 V)
		$200 \text{ ps} (CPU \text{ clock} - 5 \text{ MHz})/CC - 1.8 \laple to 5.5 \lambda)$
		• Multiplier: 16 bits \times 16 bits \rightarrow 32 bits
		• Multiplier. To bits \times To bits \rightarrow 32 bits • Multiplicaccumulate instruction: 16 bits \times 16 bits \pm 32 bits \rightarrow 32 bits
		Operating mode: Single-chip mode (address space: 1 Mbyte)
Momony		Pefer to Table 1 2 Broduct List
Memory	data flash	
Voltage	Voltage detection	Power-on reset
detection	circuit	 Voltage detection with three check points (the detection levels for voltage
		detection 0 and voltage detection 1 can be selected.)
I/O ports	Programmable	Input only: 1
	I/O ports	CMOS I/O: 59, selectable pull-up resistor
		High current drive ports: 59
Clock	Clock generation	• 4 circuits: XIN clock oscillation circuit, XCIN clock oscillation circuit,
	circuits	high-speed on-chip oscillator (with frequency adjustment function),
		low-speed on-chip oscillator
		 Oscillation stop detection: XIN clock oscillation stop detection function
		• Frequency divider circuit: Divided by 1, 2, 4, 8, or 16 can be selected
		 Low-power mode: Standard operating mode (high-speed clock, low-speed
		clock, high-speed on-chip oscillator, low-speed on-chip
		oscillator), wait mode, stop mode
Interrupts		Number of interrupt vectors: 69
		• External interrupt inputs: 9 (INT × 5, key input × 4)
		Priority levels: 7
Event link conti	roller (ELC)	• Events output from peripheral functions can be linked to events input to
		different peripheral functions.
		(30 sources × 10 types of event link operations)
		Events can be handled independently from interrupt requests.
Watchdog time	r	• 14 bits × 1
		Selectable reset start function
		Selectable low-speed on-chip oscillator for the watchdog timer
DTC (data tran	sfer controller)	• 1 channel
		Activation sources: 27
		Transfer modes: 2 (normal mode, repeat mode)
Timer	Timers RJ_0	16 bits x 1: 1 circuit integrated on-chip
		Timer mode (periodic timer), pulse output mode (output level inverted every
		period), event counter mode, pulse width measurement mode, pulse period
		measurement mode
	Timer RB2_0	16 bits x 1: 1 circuit integrated on-chip
		Timer mode (periodic timer), programmable waveform generation mode
		(PWM output), programmable one-shot generation mode, programmable wait
		one-shot generation mode
	Timers RC_0	16 bits (with 4 capture/compare registers) × 1: 1 circuit integrated on-chip
		Timer mode (input capture function, output compare function), PWM mode
		(output: 3 pins), PWM2 mode (PWM output: 1 pin)
	Timer RE2	8 bits × 1
		Compare match timer mode, real-time clock mode



1.3 Block Diagram

Figure 1.2 shows the Block Diagram.



Figure 1.2 Block Diagram



Dort Din No.		INT		UART0			UART2												
Роп	Pin No.	INT0	INT1	INT2	INT3	INT4	TXD_0	TXD_1	RXD_0	RXD_1	CLK_0	CLK_1	TXD2	RXD2	CTS2	RTS2	SDA2	SCL2	CLK2
P0 0	56																		
P0 1	55							TXD 1											
P0_2	54									RXD 1								-	
P0 3	53									_		CLK 1							
P0_4	52																		
P0_5	51																		
P0_6	50																		
F0_0	30																	├ ────	
FU_7	49																	├ ────	
P1_0	48																	ļ'	
P1_1	47																	<u> </u>	
P1_2	46																	└─── ′	
P1_3	45																	ļ'	
P1_4	44						TXD_0											<u> </u>	
P1_5	43		INT1						RXD_0									<u> </u>	
P1_6	42										CLK_0							'	
P1_7	41		INT1															'	
P2_0	27		INT1															'	
P2_1	26																	ļ'	
P2_2	25																	 '	
P2_3	24			ļ														 	
P2_4	23			ļ														 	
P2_5	22			ļ														<u> </u>	
P2_6	21			ļ														<u> </u>	
P2_7	20																	<u> </u>	
P3_0	1																	'	
P3_1	29																		
P3_2	64		INT1	INT2															
P3_3	19				INT3										CTS2	RTS2			
P3_4	18												TXD2	RXD2			SDA2	SCL2	
P3_5	17																		CLK2
P3_6	28																		
P3_7	16												TXD2	RXD2			SDA2	SCL2	
P4_2	2																		
P4_3	4																		
P4_4	5																		
P4_5	40	INT0												RXD2				SCL2	
P4_6	9																		
P4_7	7																		
P5_0	15																		
P5_1	14																		
P5_2	13																		
P5_3	12																		
P5_4	11																		
P5_6	63																		
P5_7	62																		
P6_0	61																		
P6_1	60																		
P6_2	59											CLK_1							
P6_3	58			1				TXD_1											
P6_4	57							_		RXD_1									
P6 5	39			1		INT4						CLK 1							CLK2
P6 6	38	-		INT2	1	1		1					TXD2	1	1		SDA2		
P6 7	37	-		1	INT3	1		1				1	1	1	1			<u> </u>	
P8 0	36																		
P8 1	35			<u> </u>															
P8 2	34																		
P8 3	33																		
P8 4	32	-	-	1			-		-	-	-					-	-		
P8 5	31									-							-	<u> </u>	
F0_0	20																	┝───┘	
P0_0	30			I														1	

Table 1.4 Pin Name Information by Pin Number (INT, URAT0, and UART2)



Dert	Die Me			Time	er RC	Timer RE2 Others					
Port	PIN NO.	TRCCLK_0	TRCIOA_0	TRCIOB_0	TRCIOC_0	TRCIOD_0	TRCTRG_0	TMRE2O	Others		
P0_0	56		TRCIOA_0				TRCTRG_0		AN7		
P0 1	55		TRCIOA 0				TRCTRG 0		AN6		
P0.2	54						TRCTRG 0		AN5		
P0 3	53		inteleri_e	TRCIOR 0					AN4		
P0_3	50							TMPE2O	AN2		
F0_4	52			TRCIOB_0				TWIKE20	ANG		
P0_5	51			TRCIOB_0					AN2		
P0_6	50					TRCIOD_0			AN1		
P0_7	49				TRCIOC_0				AN0		
P1_0	48					TRCIOD_0			AN8	KI0	
P1_1	47		TRCIOA_0				TRCTRG_0		AN9	KI1	
P1_2	46			TRCIOB_0					AN10	KI2	
P1_3	45				TRCIOC_0				AN11	KI3	
P1_4	44	TRCCLK_0									
P1 5	43										
P1.6	42								IVREF1		CHOO
D1 7	44								IVCMD1		CH01
F1_/	41			TROIDE					IVCIMET		CHUI
P2_0	27			TRCIOB_0							CH16
P2_1	26				TRCIOC_0						CH17
P2_2	25					TRCIOD_0					CH18
P2_3	24										CH19
P2_4	23										CH20
P2_5	22										CH21
P2_6	21										CH22
P2 7	20										CH23
P3_0	1										CH24
P3 1	20										CH10
P2_0	23										CLIDE
P3_2	64										CH25
P3_3	19	TRCCLK_0							IVCMP3		
P3_4	18				TRCIOC_0				IVREF3		
P3_5	17					TRCIOD_0					
P3_6	28										CH11
P3_7	16										
P4_2	2								VREF		
P4_3	4								XCIN		
P4 4	5								XCOUT		
P4 5	40								ADTRG		CH02
P4 6	Q								XIN		
D4 7	7								YOUT		
PF_0	15	TROCIKA							7001		
P5_0	15	TRUCLK_0									
P5_1	14		TRCIOA_0				TRCTRG_0				
P5_2	13			TRCIOB_0							
P5_3	12				TRCIOC_0						
P5_4	11					TRCIOD_0					
P5_6	63										CH27
P5_7	62										CH28
P6_0	61							TMRE2O			CH31
P6 1	60										CH32
P6 2	59										CH33
P6 3	58			1			1			1	CH34
PC_3	50										CHOF
F0_4	07			TROIDE							01/30
P6_5	39			TRCIOB_0							CH03
P6_6	38				TRCIOC_0						CH04
P6_7	37					TRCIOD_0					CH05
P8_0	36										CH06
P8_1	35										CH07
P8_2	34										CHxA0
P8 3	33										CHxA1
P8 4	32										CHxB
P8 5	31			1			1			1	CHYC
P0_3	20										CHOO
P6_6	30										CH08

Table 1.6 Pin Name Information by Pin Number (Timer RC, Timer RE2, and Others)



1.5 Pin Functions

Tables 1.7 and 1.8 list Pin Functions.

Table 1.7	Pin Functions	(1)
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Item	Pin Name	I/O	Description
Power supply input	VCC, VSS	_	Apply 1.8 V through 5.5 V to the VCC pin. Apply 0 V to the VSS pin.
Analog power supply	AVCC, AVSS	—	Power supply input for the A/D converter.
input			Connect a capacitor between pins AVCC and AVSS.
Reset input	RESET	I	Applying a low level to this pin resets the MCU.
MODE	MODE	I	Connect this pin to the VCC pin via a resistor.
XIN clock input	XIN	I	I/O for the XIN clock generation circuit.
XIN clock output	XOUT	I/O	Connect a ceramic resonator or a crystal oscillator
			between pins XIN and XOUT. (1)
			leave the XOLIT pin open
XCIN clock input	XCIN	1	I/O for the XCIN clock generation circuit
XCIN clock output	XCOUT	1/0	Connect a crystal oscillator between pins XCIN and
	10001	1/0	XCOUT. ⁽¹⁾
			To use an external clock, input it to the XCOUT pin and
			leave the XCIN pin open.
INT interrupt input	INT0 to INT4	I	INT interrupt input.
Key input interrupt	KI0 to KI3	I	Key input interrupt input.
Timer RJ_0	TRJIO_0	I/O	Input/output for timer RJ.
	TRJO_0	0	Output for timer RJ.
Timer RB2_0	TRBO_0	0	Output for timer RB2.
Timer RC_0	TRCCLK_0	I	External clock input.
	TRCTRG_0	I	External trigger input.
	TRCIOA_0, TRCIOB_0, TRCIOC_0, TRCIOD_0	I/O	Input/output for timer RC.
Timer RE2	TMRE2O	0	Divided clock output.
Serial interface	CLK_0, CLK_1	I/O	Transfer clock input/output.
(UART0)	RXD_0, RXD_1	I	Serial data input.
	TXD_0, TXD_1	0	Serial data output.
Serial interface	CTS2	I	Input for transmission control.
(UAR12)	RTS2	0	Output for reception control.
	SCL2	I/O	I ² C mode clock input/output.
	SDA2	I/O	I ² C mode data input/output.
	RXD2	I	Serial data input.
	TXD2	0	Serial data output.
	CLK2	I/O	Transfer clock input/output.
Synchronous serial	SSI_0	I/O	Data input/output.
communication unit	SCS_0	I/O	Chip-select input/output.
(550_0)	SSCK_0	I/O	Clock input/output.
	SSO_0	I/O	Data input/output.
I ² C bus (I ² C_0)	SCL_0	I/O	Clock input/output.
. ,	SDA_0	I/O	Data input/output.
Reference voltage input	VREF	I	Reference voltage input for the A/D converter.

Note:

1. Contact the oscillator manufacturer for oscillation characteristics.



Address	Symbol	Register Name	After Reset	Remarks
0003Ah	VW2C	Voltage Monitor 2 Circuit Control Register	10001010b	
0003Bh				
0003Ch				
0003Dh				
0003Eb				
0003Eh				
0003111				
0004011		Interrupt Control Degister	00h	
00041h	FMRDYIC	Interrupt Control Register	UUN	
00042h				
00043h				
00044h				
00045h				
00046h	INT4IC	Interrupt Control Register	00h	
00047h	TRCIC_0	Interrupt Control Register	00h	
00048h				
00049h				
0004Ah	TRE2IC	Interrupt Control Register	00h	
0004Bh	U2TIC	Interrupt Control Register	00h	
0004Ch	U2RIC	Interrupt Control Register	00h	
0004Dh	KUPIC	Interrupt Control Register	00h	
0004Fh	ADIC	Interrupt Control Register	00h	1
0004Eb	SSUIC 0/IICIC 0	Interrupt Control Register	00h	
000506	00010_0/11010_0		0011	
000501		Interrunt Control Register	00b	
000511		Interrupt Control Register	001	
000520			001	
00053h		Interrupt Control Register	00n	
00054h	U0RIC_1	Interrupt Control Register	00h	
00055h	INT2IC	Interrupt Control Register	00h	
00056h	TRJIC_0	Interrupt Control Register	00h	
00057h				
00058h	TRB2IC_0	Interrupt Control Register	00h	
00059h	INT1IC	Interrupt Control Register	00h	
0005Ah	INT3IC	Interrupt Control Register	00h	
0005Bh				
0005Ch				
0005Dh	INTOIC	Interrupt Control Register	00h	
0005Eh	U2BCNIC	Interrupt Control Register	00h	
0005Fh				
00060h				
00061h				
00062h				
00063h				
00064h				
00004h				
0000011				
0000011			1	
0000011				
000690				
0006Ah				
0006Bh				
0006Ch			1	
0006Dh				
0006Eh				
0006Fh				
00070h				
00071h				
00072h	VCMP1IC	Interrupt Control Register	00h	
00073h	VCMP2IC	Interrupt Control Register	00h	
00074h				
00075h	TSCUIC	Interrupt Control Register	00h	
00076h				
00077h				
00078h				
000706			1	
0001911				

Table 3.2SFR Information (2) (1)

Note:

Address	Symbol	Register Name	After Reset	Remarks
0023Ah	MSTCR2	Module Standby Control Register 2	00h	
0023Bh	MSTCR3	Module Standby Control Register 3	00h	
0023Ch	MSTCR4	Module Standby Control Register 4	00h	
002304				
0023011				
0023EN				
0023Fh				
00240h				
00241h				
00242h				
00243h				
00244h				
00245h				
00245h				
0024011				
00247h				
00248h				
00249h				
0024Ah				
0024Bh				
0024Ch				
0024Dh				
0024Fb				
0024Eb				
0024111				
00250h				
00251h	507		(0000)/00/	
00252h	FST	Flash Memory Status Register	10000X00b	
00253h				
00254h	FMR0	Flash Memory Control Register 0	00h	
00255h	FMR1	Flash Memory Control Register 1	00h	
00256h	FMR2	Flash Memory Control Register 2	00h	
00257h	1	,		
00258b				
002506	1			
002090				
0025Ah				
0025Bh				
0025Ch				
0025Dh				
0025Eh				
0025Fh				
00260b		Address Match Interrupt Address OL Register	XXXXh	
002616				
0020111		Address Match Interrupt Address OLL Deviator	000022226	
00262h		Address Match Interrupt Address UH Register		
00263h	AIENU	Address Match Interrupt Enable 0 Register	UUN	
00264h	AIADR1L	Address Match Interrupt Address 1L Register	XXXXh	
00265h				
00266h	AIADR1H	Address Match Interrupt Address 1H Register	0000XXXXb	
00267h	AIEN1	Address Match Interrupt Enable 1 Register	00h	
00268h				
00269h	ł			
002645				
0020411	1			
002001				
0026Ch				
0026Dh				
0026Eh				
0026Fh				
00270h				
00271h				
00272h	1			
00273b				
002746	+			L
0027411				
002750				
00276h				
00277h				
00278h				
00279h				
0027Ah				
0027Bh	1			
0027Ch				
002706	+			L
002701				
0027En				
0027Fh				
X: Undefine	ed			
Note:				

SFR Information (8) ⁽¹⁾ Table 3.8



Address	Symbol	Register Name	After Reset	Remarks
002C0h	PUR0	Pull-Up Control Register 0	00h	
002C1h	PUR1	Pull-Up Control Register 1	00h	
002C2h	PUR2	Pull-Up Control Register 2	00h	
002C3h				
002C4h				
002C5h				
002C6h				
002C7h				
002C8h	P1DRR	Port P1 Drive Capacity Control Register	00h	
002C9h	P2DRR	Port P2 Drive Capacity Control Register	00h	
002CAh				
002CBh	2224			
002CCh	DRR0	Drive Capacity Control Register 0	00h	
002CDh	DRR1	Drive Capacity Control Register 1	00h	
002CEN	DRRZ	Drive Capacity Control Register 2	oon	
0020FI		Input Throshold Control Register 0	00b	
002D011		Input Threshold Control Register 1	00h	
002D111		Input Threshold Control Register 7	00b	
002D2h	V L1 L			
002D4h				
002D5h				
002D6h				
002D7h				
002D8h				
002D9h				
002DAh				
002DBh				
002DCh				
002DDh				
002DEh				
002DFh	DODTO			
002E0h	PORIO	Port PU Register	XXh	
002E1h	PUKI1	Port P1 Kegister		
002E2N		Port P1 Direction Register	00h	
002E30	PORT2	Port P2 Register	XXh	
002E411	PORT3	Port P3 Register	XXh	
002E6h	PD2	Port P2 Direction Register	00h	
002F7h	PD3	Port P3 Direction Register	00h	
002E8h	PORT4	Port P4 Register	XXh	
002E9h	PORT5	Port P5 Register	XXh	
002EAh	PD4	Port P4 Direction Register	00h	
002EBh	PD5	Port P5 Direction Register	00h	
002ECh	PORT6	Port P6 Register	XXh	
002EDh				
002EEh	PD6	Port P6 Direction Register	00h	
002EFh				
002F0h	PORT8	Port P8 Register	XXh	
002F1h	550			
002F2h	PD8	Port P8 Direction Register	uun	
002F3h				
002F4N				
002550				
002F011				
002F8h				
002F9h				
002FAh				
002FBh				
002FCh				
002FDh				
002FEh				
002FFh				
00300h				
to				
003FFh				

SFR Information (10) ⁽¹⁾ Table 3.10



Address	Symbol	Register Name	After Reset	Remarks
00400h	On-chip RAM	On-chip RAM		
to	on onp to an			
052EEb				
05400b				
0340011				
069FFI			0.01	
06A00h	ELSELRO	Event Output Destination Select Register 0	UUN	
06A01h	ELSELR1	Event Output Destination Select Register 1	00h	
06A02h	ELSELR2	Event Output Destination Select Register 2	00h	
06A03h	ELSELR3	Event Output Destination Select Register 3	00h	
06A04h	ELSELR4	Event Output Destination Select Register 4	00h	
06A05h				
06A06h				
06A07h				
06A08h	ELSELR8	Event Output Destination Select Register 8	00h	
06A09h	ELSELR9	Event Output Destination Select Register 9	00h	
06A0Ah				
06A0Bh	ELSELR11	Event Output Destination Select Register 11	00h	
06A0Ch	ELSELR12	Event Output Destination Select Register 12	00h	
06A0Dh	FLSELR13	Event Output Destination Select Register 13	00h	
0640Eh	ELGELRIO	Event Output Destination Select Register 10	00b	
0640Eh		Event Output Destination Select Register 14	00b	
06AUFII		Event Output Destination Select Register 15	001	
064100	ELSELKIO	Event Output Destination Select Register 16	oon	
06A11h				
06A12h				
06A13h				
06A14h				
06A15h				
06A16h				
06A17h				
06A18h				
06A19h				
06A1Ah				
06A1Bh				
06A1Ch				
06A1Dh				
06A1Eh				
06A1Fh				
06A20h				
06A21h				
06A22h				
06A22h				
0642311				
06A240				
00A250				
06A26h				
06A27h				
06A28h				
06A29h				
06A2Ah				
06A2Bh				
06A2Ch				
06A2Dh				
06A2Eh				
06A2Fh				
06A30h				
06A31h				
to				
06AFFh				

SFR Information (11) ⁽¹⁾ Table 3.11



Table 3.13	SFR Information (13) ⁽¹⁾
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Address	Symbol	Register Name	After Reset	Remarks
06C0Ah		Area for storing DTC transfer vector 10	XXh	
06C0Bh		Area for storing DTC transfer vector 11	XXh	
06C0Ch		Area for storing DTC transfer vector 12	XXh	
06C0Dh		Area for storing DTC transfer vector 13	XXh	
06C0Eh		Area for storing DTC transfer vector 14	XXh	
06C0Fh		Area for storing DTC transfer vector 15	XXh	
06C10h		Area for storing DTC transfer vector 16	XXh	
06C11h		Area for storing DTC transfer vector 17	XXh	
06C12h		Area for storing DTC transfer vector 18	XXh	
06C13h		Area for storing DTC transfer vector 19	XXh	
06C14h				
06C15h			100	
06C16h		Area for storing DTC transfer vector 22	XXh	
06C17h		Area for storing DTC transfer vector 23	XXh	
06C18h		Area for storing DTC transfer vector 24	XXN	
060190		Area for storing DTC transfer vector 25	XXN	
06C1Rh				
06C1Ch				
06C1Dh				
06C1Eh				
06C1Eh				
06C20h				
06C21h				
06C22h				
06C23h				
06C24h				
06C25h				
06C26h				
06C27h				
06C28h				
06C29h				
06C2Ah		Area for storing DTC transfer vector 42	XXh	
06C2Bh				
06C2Ch				
06C2Dh				
06C2Eh				
06C2Fh				
06C30h		Anna fan starian DTO transfan yn star 40	XXL	
060310		Area for storing DTC transfer vector 49	XXN	
060320		Area for staring DTC transfer vector 51	XXP	
06C34h		Area for storing DTC transfer vector 51		
06C35h		Area for storing DTC transfer vector 52	XXh	
06C36h		Area for storing DTC transfer vector 55	XXh	
06C37h				
06C38h				
06C39h	1			
06C3Ah	1			
06C3Bh	İ			
06C3Ch				
06C3Dh				
06C3Eh				
06C3Fh				
06C40h	DTCCR0	DTC Control Register 0	XXh	
06C41h	DTBLS0	DTC Block Size Register 0	XXh	
06C42h	DTCCT0	DTC Transfer Count Register 0	XXh	
06C43h	DTRLD0	DTC Transfer Count Reload Register 0	XXh	
06C44h	DTSAR0	DTC Source Address Register 0	XXXXh	
06C45h				
06C46h	DTDAR0	DTC Destination Address Register 0	XXXXh	
06C47h				
06C48h	DTCCR1	DTC Control Register 1	XXh	
06C49h	DTBLS1	DTC Block Size Register 1	XXh	

X: Undefined

Address	Symbol	Register Name	After Reset	Remarks
06C4Ah	DTCCT1	DTC Transfer Count Register 1	XXh	
06C4Bh	DTRLD1	DTC Transfer Count Reload Register 1	XXh	
06C4Ch	DTSAR1	DTC Source Address Register 1	XXXXh	
06C4Dh	1			
06C4Eh	DTDAR1	DTC Destination Address Register 1	XXXXh	
06C4Fh	1			
06C50h	DTCCR2	DTC Control Register 2	XXh	
06C51h	DTBL S2	DTC Block Size Register 2	XXh	
06C52h	DTCCT2	DTC Transfer Count Register 2	XXh	
060521		DTC Transfer Count Reload Register 2	XXh	
0605311		DTC mansier Courre Addross Pagistar 2	XXXXk	
0605541	DIGARZ	DIO Source Address Register 2	~~~~	
000550		DTC Destination Address Desistant	VVVVb	
06056h	DTDAR2	Destination Address Register 2	777YU	
06C57h	570054		10.4	
06C58h	DTCCR3	DIC Control Register 3	XXh	
06C59h	DTBLS3	DTC Block Size Register 3	XXh	
06C5Ah	DTCCT3	DTC Transfer Count Register 3	XXh	
06C5Bh	DTRLD3	DTC Transfer Count Reload Register 3	XXh	
06C5Ch	DTSAR3	DTC Source Address Register 3	XXXXh	
06C5Dh				
06C5Eh	DTDAR3	DTC Destination Address Register 3	XXXXh	
06C5Fh	1	-		
06C60h	DTCCR4	DTC Control Register 4	XXh	
06C61h	DTBLS4	DTC Block Size Register 4	XXh	
06C62h	DTCCT4	DTC Transfer Count Register 4	XXh	
06063h	DTRI D4	DTC Transfer Count Reload Register 4	XXh	
060646	DTSARA	DTC Source Address Register /	YYYYh	
060656	DI SAN4	DIO OUTLE AUTESS KEYISTEL 4		
060001		DTC Destination Address Register 4	VVVVh	
	DIDAK4	Destination Address Register 4	~~~~	
06067h	DTOODS			
06C68h	DICCR5	DTC Control Register 5	XXN	
06C69h	DTBLS5	DTC Block Size Register 5	XXh	
06C6Ah	DTCCT5	DTC Transfer Count Register 5	XXh	
06C6Bh	DTRLD5	DTC Transfer Count Reload Register 5	XXh	
06C6Ch	DTSAR5	DTC Source Address Register 5	XXXXh	
06C6Dh				
06C6Eh	DTDAR5	DTC Destination Address Register 5	XXXXh	
06C6Fh]			
06C70h	DTCCR6	DTC Control Register 6	XXh	
06C71h	DTBLS6	DTC Block Size Register 6	XXh	
06C72h	DTCCT6	DTC Transfer Count Register 6	XXh	
06C73h	DTRLD6	DTC Transfer Count Reload Register 6	XXh	
06C74h	DTSAR6	DTC Source Address Register 6	XXXXh	
06C75h				
060765		DTC Destination Address Register 6	XXXXh	
060775		Dio Destination Autress Register 0		
060705	DTCCP7	DTC Control Register 7	YYh .	
060705		DTC Control Register /	7711 776	
000790	DIDLO/			
06C7Bh		DTC Transfer Count Reload Register 7	XXN	
06C7Ch	DTSAR7	DIC Source Address Register 7	XXXXh	
06C7Dh				
06C7Eh	DTDAR7	DTC Destination Address Register 7	XXXXh	
06C7Fh				
06C80h	DTCCR8	DTC Control Register 8	XXh	
06C81h	DTBLS8	DTC Block Size Register 8	XXh	
06C82h	DTCCT8	DTC Transfer Count Register 8	XXh	
06C83h	DTRLD8	DTC Transfer Count Reload Register 8	XXh	
06C84h	DTSAR8	DTC Source Address Register 8	XXXXh	
06C85h	1	č		
06C86h	DTDAR8	DTC Destination Address Register 8	XXXXh	
06C.87h	1			
060885	DTCCR9	DTC Control Register 9	XXh	
060001		DTC Block Size Register 9	XXh	
000090	DIDLOS	DTC Transfor Count Pogister 0	XXh	
		DTC Transfer Count Reload Register 9		
06C8Ch	DISAR9	DTC Source Address Register 9	XXXXh	
06C8Dh				
06C8Eh	DTDAR9	DTC Destination Address Register 9	XXXXh	
06C8Fh				
X: Undefine	ed			

Table 3.14SFR Information (14) (1)

Note:



Address	Symbol	Register Name	After Reset	Remarks
06C90h	DTCCR10	DTC Control Register 10	XXh	
06C91h	DTBLS10	DTC Block Size Register 10	XXh	
06C92h	DTCCT10	DTC Transfer Count Register 10	XXh	
06C93h	DTRI D10	DTC Transfer Count Reload Register 10	XXh	
06C94h	DTSAR10	DTC Source Address Register 10	XXXXh	
06C95h	DIGNICIO		70000ii	
06C95h		DTC Destinction Address Register 10	VVVVb	
060901	DIDARIO	DTC Destination Address Register TO	~~~~	
0609711	DTOOD44		204	
060980			AAn	
06C99h	DIBLS11	DTC Block Size Register 11	XXN	
06C9Ah	DICCI11	DTC Transfer Count Register 11	XXh	
06C9Bh	DTRLD11	DTC Transfer Count Reload Register 11	XXh	
06C9Ch	DTSAR11	DTC Source Address Register 11	XXXXh	
06C9Dh				
06C9Eh	DTDAR11	DTC Destination Address Register 11	XXXXh	
06C9Fh				
06CA0h	DTCCR12	DTC Control Register 12	XXh	
06CA1h	DTBLS12	DTC Block Size Register 12	XXh	
06CA2h	DTCCT12	DTC Transfer Count Register 12	XXh	
06CA3h	DTRLD12	DTC Transfer Count Reload Register 12	XXh	
06CA4h	DTSAR12	DTC Source Address Register 12	XXXXh	
06CA5h	1			
06CA6h	DTDAR12	DTC Destination Address Register 12	XXXXh	
06CA7h				
06CA8h	DTCCR13	DTC Control Register 13	XXh	
06CA9h	DTBI S13	DTC Block Size Register 13	XXh	
06CAAb	DTCCT13	DTC Transfer Count Register 13	XXh	
06CABb		DTC Transfer Count Reload Register 13	XXh	
06CACh	DTSAR13	DTC Source Address Register 13	XXXXb	
06CADh	DIGARIS	DTO Source Address Register To		
OCADI		DTC Destinction Address Register 12	VVVVb	
06CAEh	DIDARIS	DTC Destination Address Register 13	~~~~	
06CR0h	DTCCP14	DTC Control Register 14	VVb.	
06CB0II	DTCCR14	DTC Control Register 14		
06CB1II	DIBL314	DTC Block Size Register 14		
06CB2II	DTCCT14	DTC Transfer Count Register 14		
060830	DTRLD14	DTC Transfer Count Reload Register 14		
06CB4II	DISAR14	DTC Source Address Register 14	~~~~	
06CB5N	DTDAD44	DTO Destination Address Desister 44	VVVVL	
0600076	DIDAR14	DTC Destination Address Register 14	****	
060870	DTOOD45	DTO Operated Deviates 45	XXL	
06CB6II	DICCRIS	DTC Control Register 15		
06CB9h	DIBLS15	DTC Block Size Register 15	XXN	
06CBAn	DICCI15	DTC Transfer Count Register 15	XXN	
06CBBh	DIRLD15	DTC Transfer Count Reload Register 15	XXh	
06CBCh	DTSAR15	DTC Source Address Register 15	XXXXh	
06CBDh				
06CBEh	DTDAR15	DTC Destination Address Register 15	XXXXh	
06CBFh				
06CC0h	DTCCR16	DTC Control Register 16	XXh	
06CC1h	DTBLS16	DTC Block Size Register 16	XXh	
06CC2h	DTCCT16	DTC Transfer Count Register 16	XXh	
06CC3h	DTRLD16	DTC Transfer Count Reload Register 16	XXh	
06CC4h	DTSAR16	DTC Source Address Register 16	XXXXh	
06CC5h				
06CC6h	DTDAR16	DTC Destination Address Register 16	XXXXh	
06CC7h				
06CC8h	DTCCR17	DTC Control Register 17	XXh	
06CC9h	DTBLS17	DTC Block Size Register 17	XXh	
06CCAh	DTCCT17	DTC Transfer Count Register 17	XXh	
06CCBh	DTRLD17	DTC Transfer Count Reload Register 17	XXh	
06CCCh	DTSAR17	DTC Source Address Register 17	XXXXh	
06CCDh]			
06CCEh	DTDAR17	DTC Destination Address Register 17	XXXXh	
06CCFh	1			

Table 3.15SFR Information (15) (1)

X: Undefined

Note:



4. Electrical Characteristics

4.1 Absolute Maximum Ratings

Table 4.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		–0.3 to 6.5	V
ICEVcc				
VI	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	$-40^{\circ}C \le Topr \le 85^{\circ}C$	500	mW
Topr	Operating ambient temperature		-20 to 85 (N version)/	°C
			-40 to 85 (D version)	
Tstg	Storage temperature		-65 to 150	°C



Table 4.5Flash Memory (Program ROM) Characteristics
(Vcc = 2.7 V to 5.5 V, Topr =-20°C to 85°C (N version)/-40°C to 85°C (D version),
unless otherwise specified)

Paramotor	Conditions	Standard			
Falameter	Conditions	Min.	Тур.	Max.	Onit
Program/erase endurance (1)		1,000 (2)	_	—	times
Byte program time (Program and erase endurance \leq 100 times)		_	_	_	μs
Byte program time (Program and erase endurance \leq 1,000 times)		—	_	_	μs
Word program time (Program and erase endurance \leq 100 times)	Topr = 25°C, Vcc = 5.0 V	_	100	200	μs
Word program time (Program and erase endurance \leq 100 times)		_	100	400	μs
Word program time (Program and erase endurance \leq 1,000 times)		_	100	650	μs
Block erase time		—	0.3	4	S
Time delay from suspend request until suspend		—	_	5 + CPU clock × 3 cycles	ms
Interval from erase start/restart until following suspend request		0	—	—	μs
Time from suspend until erase restart		—	_	30 + CPU clock × 1 cycle	μs
Time from when command is forcibly terminated until reading is enabled		—	_	30 + CPU clock × 1 cycle	μs
Program, erase voltage		2.7		5.5	V
Read voltage		1.8	_	5.5	V
Program, erase temperature		-20 (N ver.) -40 (D ver.)	—	85	°C
Data hold time ⁽⁶⁾	Ambient temperature = $55^{\circ}C^{(7)}$	20	_	_	year
	Parameter Program/erase endurance (1) Byte program time (Program and erase endurance ≤ 100 times) Byte program time (Program and erase endurance ≤ 1,000 times) Word program time (Program and erase endurance ≤ 100 times) Word program time (Program and erase endurance ≤ 100 times) Word program time (Program and erase endurance ≤ 100 times) Word program time (Program and erase endurance ≤ 1,000 times) Block erase time Time delay from suspend request until suspend Interval from erase start/restart until following suspend request Time from when command is forcibly terminated until reading is enabled Program, erase voltage Read voltage Program, erase temperature Data hold time ⁽⁶⁾	ParameterConditionsProgram/erase endurance (1)IByte program time (Program and erase endurance ≤ 100 times)IByte program time (Program and erase endurance $\leq 1,000$ times)Topr = 25°C, Vcc = 5.0 VWord program time (Program and erase endurance ≤ 100 times)Topr = 25°C, Vcc = 5.0 VWord program time (Program and erase endurance ≤ 100 times)Topr = 25°C, Vcc = 5.0 VWord program time (Program and erase endurance ≤ 100 times)IWord program time (Program and erase endurance $\leq 1,000$ times)IBlock erase time Time delay from suspend request until suspendIInterval from erase start/restart until following suspend requestITime from when command is forcibly terminated until reading is enabledIProgram, erase voltage Read voltageIProgram, erase temperature $= 55°C (7)$ Ambient temperature $= 55°C (7)$	ParameterConditionsProgram/erase endurance (1)1,000 (2)Byte program time (Program and erase endurance \leq 100 times)—Byte program time (Program and erase endurance \leq 1,000 times)—Word program time (Program and erase endurance \leq 1,000 times)Topr = 25°C, Vcc = 5.0 VWord program time (Program and erase endurance \leq 100 times)—Word program time (Program and erase endurance \leq 100 times)—Word program time (Program and erase endurance \leq 100 times)—Word program time (Program and erase endurance \leq 1,000 times)—Word program time (Program and erase endurance \leq 1,000 times)—Block erase time Time delay from suspend request until suspend—Interval from erase start/restart until following suspend request—Time from suspend until erase restart Time from suspend until erase restart—Time from when command is forcibly terminated until reading is enabled—Program, erase voltage Program, erase temperature = 55°C (7)—Data hold time (6) Ambient temperature = 55°C (7)20	Standau ConditionsStandau Min.Standau Min.Program/erase endurance (1)ConditionsMin.Typ.Byte program time (Program and erase endurance ≤ 100 times)Byte program time (Program and erase endurance $\leq 1,000$ times)Word program time (Program and erase endurance ≤ 100 times)Topr = 25°C, Vcc = 5.0 V100Word program time (Program and erase endurance ≤ 100 times)Topr = 25°C, Vcc = 5.0 V100Word program time (Program and erase endurance ≤ 100 times)100Word program time (Program and erase endurance $\leq 1,000$ times)100Interval from suspend request until suspend0.3Interval from suspend request tollowing suspend requestTime from when command is forcibly terminated until reading is enabledProgram, erase voltage2.7Program, erase voltage1.8Data hold time (6)Ambient temperature $= 55°C$ (7)20	ParameterConditionsStandardProgram/erase endurance (1)ConditionsMin.Typ.Max.Program time (Program and erase endurance ≤ 100 times)—————Byte program time (Program and erase endurance $\leq 1,000$ times)—————Word program time (Program and erase endurance ≤ 100 times)Topr = 25°C, Vcc = 5.0 V—100200Word program time (Program and erase endurance ≤ 100 times)Topr = 25°C, Vcc = 5.0 V—100400Word program time (Program and erase endurance ≤ 100 times)—100400Word program time (Program and erase endurance $\leq 1,000$ times)—100650Word program time (Program and erase endurance $\leq 1,000$ times)—0——Word program time (Program and erase endurance $\leq 1,000$ times)—0.34Time delay from suspend request until suspend—0.34Time delay from suspend request until suspend until erase restart——30 + CPU clock × 1 cycleTime from when command is forcibly terminated until reading is enabled———30 + CPU clock × 1 cycleTime from when command is forcibly terminated until reading is enabled———30 + CPU clock × 1 cycleProgram, erase voltage—1.8—5.5=Program, erase temperature $= 55°C (7)$ —20—— </td

Notes:

1. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 100 or 1,000), each block can be erased n times. For example, if 1,024 1byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

2. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

- 3. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
- 4. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 5. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 6. The data hold time includes time that the power supply is off or the clock is not supplied.
- 7. The data hold time includes 7,000 hours under an environment of ambient temperature 85°C.



Table 4.6Flash Memory (Data flash Block A to Block D) Characteristics
(Vcc = 2.7 V to 5.5 V, Topr = -20°C to 85°C (N version)/-40°C to 85°C (D version),
unless otherwise specified)

Symbol	Paramotor	Conditions	Standard			
Symbol	Falantelei	Conditions	Min.	Тур.	Max.	Onit
_	Program/erase endurance (1)		10,000 (2)	_	—	times
—	Byte program time (Program and erase endurance \leq 1,000 times)		_	160	950	μs
_	Byte program time (Program and erase endurance > 1,000 times)		_	300	950	μs
	Block erase time (Program and erase endurance \leq 1,000 times)		_	0.2	1	S
—	Block erase time (Program and erase endurance > 1,000 times)		_	0.3	1	S
td(SR-SUS)	Time delay from suspend request until suspend		—	_	3 + CPU clock × 3 cycles	ms
—	Interval from erase start/restart until following suspend request		0	—	—	μs
_	Time from suspend until erase restart		—	_	30 + CPU clock × 1 cycle	μs
td(CMDRST -READY)	Time from when command is forcibly terminated until reading is enabled		—	—	30 + CPU clock × 1 cycle	μs
_	Program, erase voltage		2.7	_	5.5	V
_	Read voltage		1.8		5.5	V
—	Program, erase temperature		-20 (N ver.) -40 (D ver.)	—	85	°C
-	Data hold time ⁽⁶⁾	Ambient temperature = $55^{\circ}C^{(7)}$	20	_	_	year

Notes:

1. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 100, 1,000 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

2. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

3. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A to D can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.

4. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.

5. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.

6. The data hold time includes time that the power supply is off or the clock is not supplied.

7. The data hold time includes 7,000 hours under an environment of ambient temperature 85° C.



Table 4.12Low-Speed On-Chip Oscillator Circuit Characteristics
(Measurement conditions: Vcc = 1.8 V to 5.5 V, Topr = -20°C to 85°C (N version)/
-40°C to 85°C (D version))

Symbol	Baramatar	Conditions		Linit			
Symbol	i didificter	Conditions	Min.	Тур.	Max.	Offic	
fLOCO	Low-speed on-chip oscillator frequency		60	125	250	kHz	
—	Oscillation stability time	Vcc = 5.0 V, Topr = 25°C	_	30	100	μs	
—	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	—	3	—	μA	

Table 4.13Power Supply Circuit Characteristics
(Measurement conditions: Vcc = 1.8 V to 5.5 V, Topr = -20°C to 85°C (N version)/
-40°C to 85°C (D version))

Symbol	Parameter	Conditions		Lloit			
Cymbol	raidifictor	Conditions	Min.	Тур.	Max.	Onit	
td(P-R)	Time for internal power supply		—	_	2,000	μs	
	stabilization during power-on ⁽¹⁾						

Note:

1. Waiting time until the internal power supply generation circuit stabilizes during power-on.



Table 4.17DC Characteristics (4) [2.7 V \leq Vcc < 3.3 V]
(Topr = -20°C to 85°C (N version)/-40°C to 85°C (D version), unless otherwise
specified))

		Conditions						Sta	Standard (4				
Symbol	Parameter		Osci	Oscillation On-		On-Chip Oscillator		Low-Power-					Unit
			XIN (2)	XCIN	High- Speed	Low- Speed	CPU Clock	Setting	Other	Min.	Typ.	Max.	
lcc	Power	High-	10 MHz	Off	Off	125 kHz	No division	—		—	3.5	10	mA
	supply current ⁽¹⁾	speed clock mode	10 MHz	Off	Off	125 kHz	Divide-by-8	_		-	1.5	7.5	mA
		High-	Off	Off	20 MHz ⁽³⁾	125 kHz	No division	-		-	7.0	15	mA
		speed on-	Off	Off	20 MHz ⁽³⁾	125 kHz	Divide-by-8	—		—	3.0	-	mA
		oscillator	Off	Off	10 MHz ⁽³⁾	125 kHz	No division	—		—	4.0	-	mA
		mode	Off	Off	10 MHz ⁽³⁾	125 kHz	Divide-by-8	-		—	1.5	-	mA
			Off	Off	4 MHz ⁽³⁾	125 kHz	Divide-by-16	MSTIIC = 1 MSTTRC = 1		-	1	-	mA
	Low- speed or chip oscillator mode Low- speed clock mode Wait mode	Low- speed on- chip oscillator mode	Off	Off	Off	125 kHz	Divide-by-8	FMR27 = 1 SVC0 = 0		—	90	390	μA
		Low- speed clock mode	Off	32 kHz	Off	Off	No division	FMR27 = 1 SVC0 = 0		_	80	400	μA
			Off	32 kHz	Off	Off	No division	FMSTP = 1 SVC0 = 0	Program operation on RAM Flash memory off	—	40	Ι	μA
		Wait mode	Off	Off	Off	125 kHz	-	VCA27 = 0 VCA26 = 0 VCA25 = 0 SVC0 = 1	While a WAIT instruction is executed Peripheral clock operation	-	15	90	μA
			Off	Off	Off	125 kHz	-	VCA27 = 0 VCA26 = 0 VCA25 = 0 SVC0 = 1	While a WAIT instruction is executed Peripheral clock off	-	4	80	μA
			Off	32 kHz	Off	Off	_	VCA27 = 0 VCA26 = 0 VCA25 = 0 SVC0 = 1	While a WAIT instruction is executed Peripheral clock off	-	3.5	-	μA
		Stop mode	Off	Off	Off	Off	_	VCA27 = 0 VCA26 = 0 VCA25 = 0 CM10 = 1	Topr = 25°C Peripheral clock off	-	2.2	6.0	μA
			Off	Off	Off	Off	_	VCA27 = 0 VCA26 = 0 VCA25 = 0 CM10 = 1	Topr = 85°C Peripheral clock off	_	30	_	μA

Notes:

1. Vcc = 2.7 V to 3.3 V, single-chip mode, output pins are open, and other pins are Vss.

2. XIN is set to square wave input.

3. fHOCO-F

4. The typical value (Typ.) indicates the current value when the CPU and the memory operate.

The maximum value (Max.) indicates the current value when the CPU, the memory, and the peripheral functions operate and the flash memory is programmed/erased.





Communication Mode)







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Renesas Electronics America Inc. 2880 Scott Boulders: 1+408-588-6130 Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220 Renesas Electronics Europe Limited Dukes Meadow, Milboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44+1628-585-900 Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +44-1628-585-900 Renesas Electronics Curope GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +44-1628-585-900 Renesas Electronics Curope GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +44-1628-585-900 Renesas Electronics (Shanghai) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China Tel: +862-10-827-1155, Tex: +486-12-827-7679 Renesas Electronics (Shanghai) Co., Ltd. Unit 204, 205, A21A Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +862-1-877-1818, Fax: +862-2-867-7858 Renesas Electronics Hong Kong Limited Unit 1001-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +862-286-9318, Fax: +862-2869-02219044 Renesas Electronics Taiwan Co., Ltd. 154, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +862-24175-9600, Fax: +886 2-8175-9670 Renesas Electronics Malaysia Sdn.Bhd. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-27-957-9309, Fax: +60-27-955-9310, Tel: +65-6278-9300, Fax: +880-2-8175-9670 Renesas Electronics Korea Co., Ltd. 11-R, Samik Lavied' or Billog, 720-2 Veoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: +60-37-955-930, Fax: +882-2558-5141